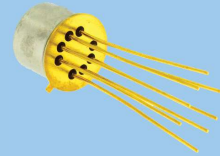




TO-5 RELAYS ESTABLISHED RELIABILITY MILITARY DPDT



SERIES	RELAY TYPE
412	DPDT basic relay
412D	DPDT relay with internal diode for coil transient suppression
412DD	DPDT relay with polarity reversal protection and coil transient suppression diode
412T	DPDT relay with internal transistor driver and coil transient suppression diode

DESCRIPTION

The TO-5 relay, originally conceived and developed by Teledyne, has become one of the industry standards for low-level switching from dry circuit to 1 ampere. Designed expressly for high-density PC board mounting, its small size and low coil power dissipation make the 412 relay one of the most versatile ultraminiature relays available.

The following unique construction features and manufacturing techniques provide excellent resistance to environmental extremes and overall high reliability.

The 412 feature:

- All welded construction.
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity.
- High force/mass ratios for resistance to shock and vibration.

- Advanced cleaning techniques provide maximum assurance of internal cleanliness.
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities.

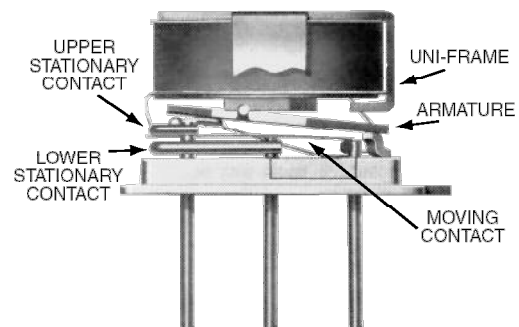
The Series 412D and 412DD relays have internal discrete silicon diodes for coil suppression and polarity reversal protection. The hybrid 412T relay features an internal silicon suppression diode and transistor driver. This hybrid package reduces required PC board floor space by reducing the number of external components needed to drive the relay.

By virtue of its inherently low intercontact capacitance and contact circuit losses, the 412 relay has proven to be an excellent ultraminiature RF switch for frequency ranges well into the UHF spectrum. A typical RF application for the TO-5 relay is in handheld radio transceivers, wherein the combined features of good RF performance, small size, low coil power dissipation and high reliability make it a preferred method of T-R switching

ENVIRONMENTAL AND PHYSICAL SPECIFICATIONS

Temperature (Ambient)	–65°C to +125°C
Vibration (General Note I)	30 g's to 3000 Hz
Shock (General Note I)	75 g's, 6ms half sine
Acceleration	50 g's
Enclosure	Hermetically sealed
Weight	0.09 oz. (2.55g) max.

INTERNAL CONSTRUCTION



SERIES 412
GENERAL ELECTRICAL SPECIFICATIONS (-65°C to +125°C unless otherwise noted) (Notes 2 & 3)

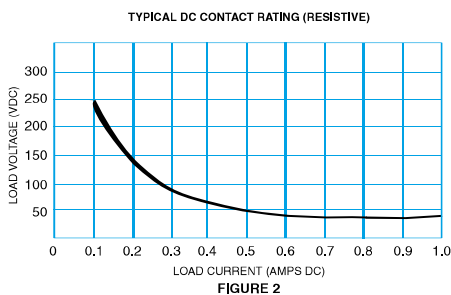
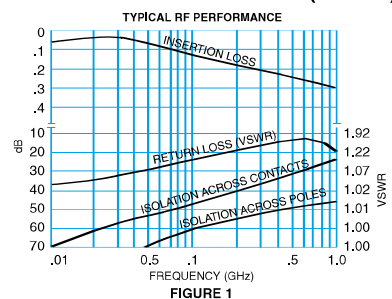
Contact Arrangement	2 Form C (DPDT)		
Rated Duty	Continuous		
Contact Resistance	0.1 ohm max. before life; 0.2 ohm max. after life at 1A/28Vdc (measured 1/8" from header)		
Contact Load Rating (DC)	Resistive: 1 A / 28 Vdc Inductive: 200 mA / 28 Vdc (320mH) Lamp: 100 mA / 28 Vdc (320mH) Low level: 10 to 50 μ A @ 10 to 50 mV		
Contact Load Rating (AC)	Resistive: 250 mA / 115Vac, 60 and 400 Hz (Case not grounded) 100 mA / 115 Vac, 60 and 400 Hz (Case grounded)		
Contact Life Ratings	10,000,000 cycles (typical) at low level 1,000,000 cycles (typical) at 0.5 A / 28 Vdc resistive 100,000 cycles min. at all other loads specified above		
Contact Overload Rating	2 A / 28 Vdc Resistive (100 cycles min.)		
Coil Operating Power	450 mW typical at nominal rated voltage		
Contact Carry Rating	Contact Factory		
Operate Time	2.0 ms max. at nominal rated coil voltage		
Release Time	412: 1.5 ms max.	412D, 412DD: 4.0 ms max.	412T: 7.5 ms max
Contact Bounce	1.5 ms max		
Intercontact Capacitance	0.4 pf typical		
Insulation Resistance	10,000 M Ω min. between mutually isolated terminals		
Dielectric Strength	500 Vrms / 60 Hz @ atmospheric pressure		
	125 Vrms / 60 Hz @ 70,000 ft		
Negative Coil Transient (Vdc) 412D, 412DD, 412T	1.0 Vdc Max.		
Diode P.I.V. (Vdc) 412D, 412DD, 412T	100 Vdc Min.		
412T Transistor Characteristics	Base Voltage to Turn Off (Vdc)	0.3 min	
	Emitter-Base breakdown Voltage (BV_{EBO}) (@25°C) (Vdc)	6.0 min	
	Collector-Base breakdown Voltage (BV_{CBO}) (@25°C & $I_c = 100 \mu$ A) (Vdc)	75 min	

412 Series

DETAILED ELECTRICAL SPECIFICATIONS (-65°C to +125°C unless otherwise noted) (Notes 3)

BASE PART NUMBERS (412, 412D, 412DD, 412T)		412-5 412D-5 412DD-5 412T-5	412-12 412D-12 412DD-12 412T-12	412-26 412D-26 412DD-26 412T-26
Coil Voltage	Nom.	5.0	12.0	26.5
	Max.	5.8	16.0	32.0
Coil Resistance (Ohms $\pm 10\%$ @25°C)	412, 412D, 412T	50	390	1560
	412DD	39	390	1560
Coil Current (412DD) (mA _{dc} @25°C)	Min.	93.2	25.6	14.8
	Max.	128.2	32.8	18.5
Coil Current (412T) (mA _{dc} @25°C) (Note 7)	Min.	82.2	26.6	14.7
	Max.	112.1	35.8	19.8
Pick-up Voltage (V _{dc} , Max)	412, 412D	3.5	9.0	18.0
	412DD	3.9	10.0	19.0
	412T (Note 7)	3.5	9.0	18.0
Drop-out Voltage (V _{dc})	412, 412D, 412T	Min.	0.14	0.41
		Max.	2.3	13.0
	412DD	Min.	0.6	1.4
		Max.	2.8	13.0

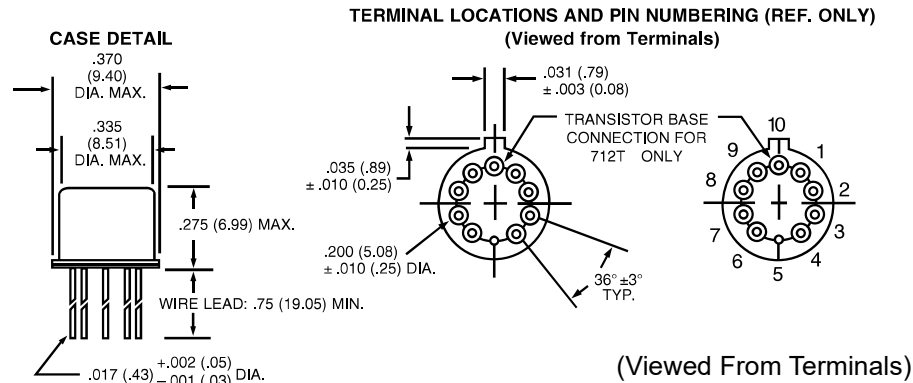
PERFORMANCE CURVES (Note 2)



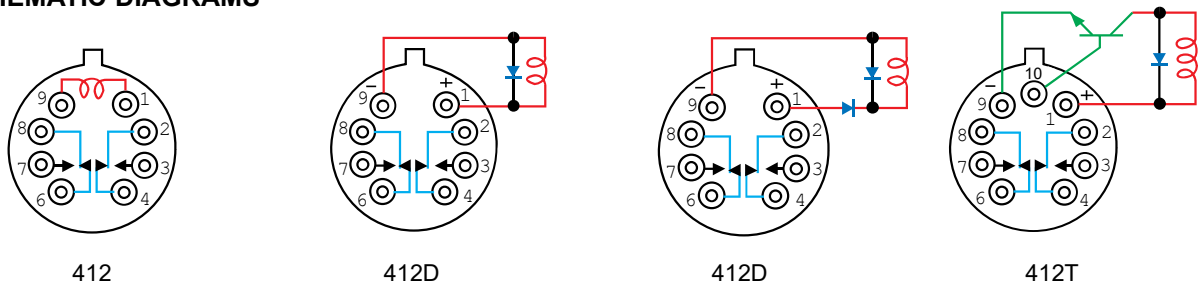
GENERAL NOTES

1. Relay contacts will exhibit no chatter in excess of 10 μ sec or transfer in excess of 1 μ sec.
2. "Typical" characteristics are based on available data and are best estimates. No on-going verification tests are performed.
3. Unless otherwise specified, parameters are initial values.
4. Relays can be supplied with a spacer pad. See appendix.

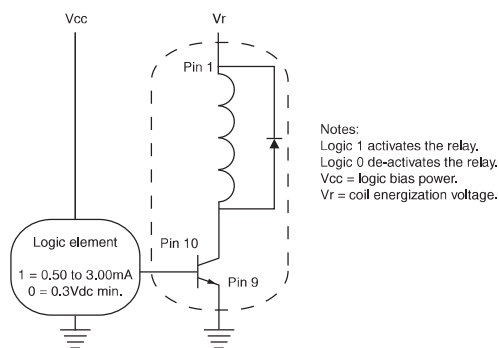
SERIES 412 OUTLINE DIMENSIONS



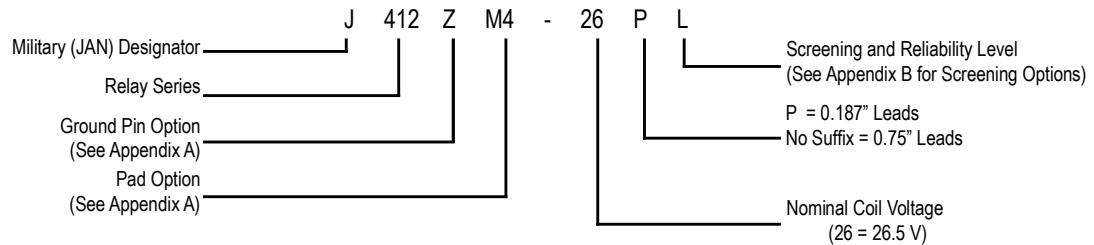
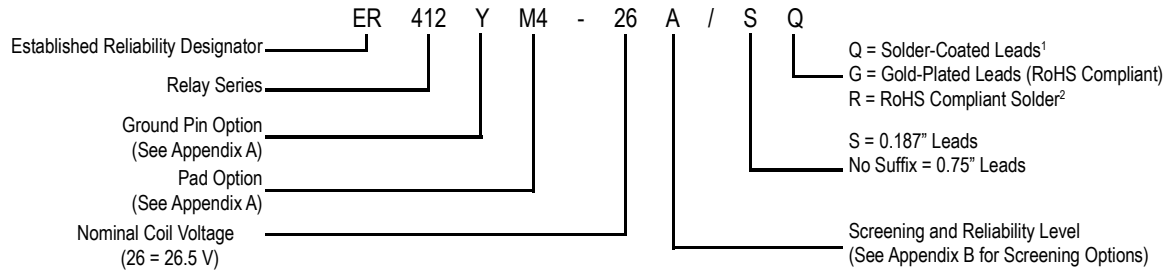
SCHEMATIC DIAGRAMS



TYPICAL LOGIC INTERFACE (See Note 8)



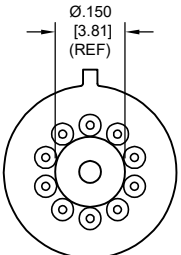
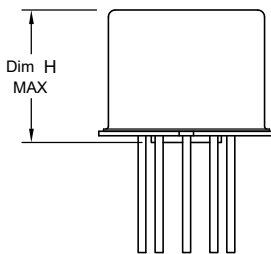
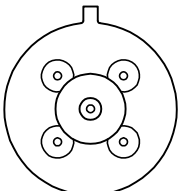
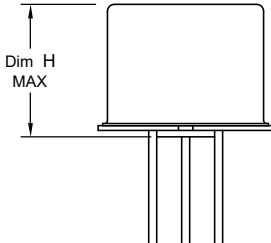
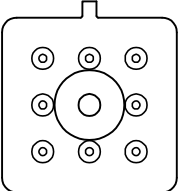
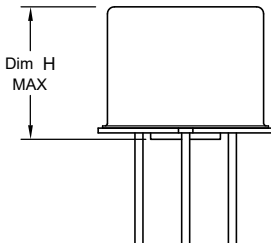
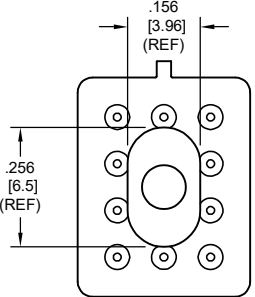
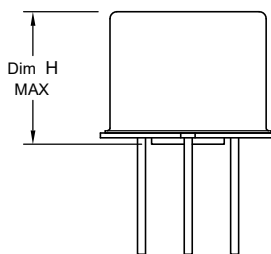
SERIES 412 PART NUMBERING SYSTEM



NOTES:

1. RELAY CONTACTS WILL EXHIBIT NO CHATTER IN EXCESS OF 10 MSEC OR TRANSFER IN EXCESS OF 1 MSEC.
2. "TYPICAL" CHARACTERISTICS ARE BASED ON AVAILABLE DATA AND ARE BEST ESTIMATES. NO ON-GOING VERIFICATION TESTS ARE PERFORMED.
3. UNLESS OTHERWISE SPECIFIED, PARAMETERS ARE INITIAL VALUES.
4. FOR REFERENCE ONLY. COIL RESISTANCE NOT DIRECTLY MEASURABLE AT RELAY TERMINALS DUE TO INTERNAL SERIES SEMICONDUCTOR. 412DD AND 412T ONLY.
5. UNLESS OTHERWISE SPECIFIED, RELAYS WILL BE SUPPLIED WITH EITHER GOLD-PLATED OR SOLDER-COATED LEADS.
6. THE SLASH AND CHARACTERS APPEARING AFTER THE SLASH ARE NOT MARKED ON THE RELAY.
7. LIMIT BASE EMITTER CURRENT TO 15 mADC.
8. APPLICABLE TO ALL COIL VOLTAGES. SEE BASE CURRENT TO TURN ON.
9. SCREENED HI-REL VERSIONS AVAILABLE. CONTACT FACTORY.

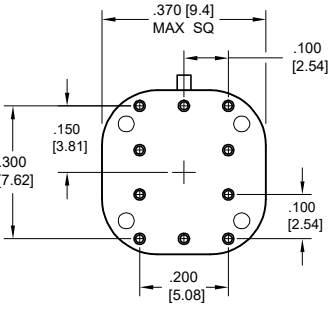
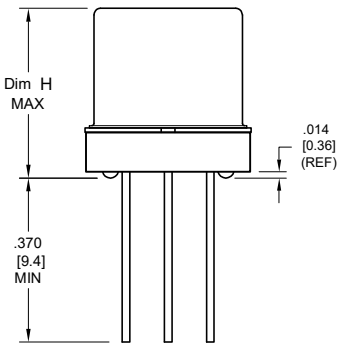
APPENDIX A : Spacer Pads

Pad designation and bottom view dimensions	Height	For use with the following:	Dim. H Max.
 “M4” Spacer Pad for TO-5		ER412	.295 (7.49)
		712, RF300, RF, RF700, RF703	.300 (7.62)
		ER422, 722	.305 (7.75)
		ER432	.400 (10.16)
		732, RF303	.410 (10.41)
		RF312	.350 (8.89)
 “M4”Spacer Pad for TO-5		ER411	.295 (7.49)
		RF311	.300 (7.62)
		RF331	.410 (10.41)
 “M4” Spacer Pad for Centigrid®		172	.305 (7.75)
		ER114, J114	.300 (7.62)
		ER134, J134	.400 (10.16)
		RF100	.315 (8.00)
		RF103	.420 (10.67)
 “M9”Spacer Pad for Centigrid®		122C, A152	.320 (8.13)
		ER116C, J116C	.300 (7.62)
		ER136C, J136C	.400 (10.16)
		RF180	.325 (8.25)
		A150	.305 (7.75)

Notes:

1. Spacer pad material: Polyester film.
2. To specify an “M4” or “M9” spacer pad, refer to the mounting variants portion of the part numbering example in the applicable datasheet.
3. Dimensions are in inches (mm).
4. Unless otherwise specified, tolerance is $\pm .010$ ” (.25 mm).
5. Add 10 m Ω to the contact resistance shown in the datasheet.
6. Add 0.01 oz. (0.25 g) to the weight of the relay assembly shown in the datasheet.

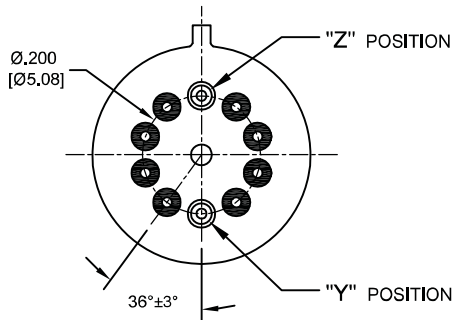
APPENDIX A : Spreader Pads

Pad designation and bottom view dimensions	Height	For use with the following:	Dim. H Max.
 "M" Spreader Pad <u>5</u>/ <u>6</u>/		ER411T, ER412, J412	.388 (9.86)
		712	.393 (9.99)
		ER432, J432	.493 (12.52)
		732	.503 (12.78)
		J421, J422, ER422, 722	.398 (10.11)

Notes:

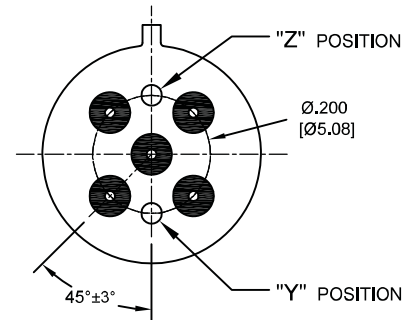
1. Spreader pad material: Diallyl Phthalate.
2. To specify an "M", "M2" or "M3" spreader pad, refer to the mounting variants portion of the part number example in the applicable datasheet.
3. Dimensions are in inches (mm).
4. Unless otherwise specified, tolerance is $\pm .010$ " (0.25 mm).
- 5/. Add 25 m Ω to the contact resistance shown in the datasheet.
- 6/. Add .01 oz. (0.25 g) to the weight of the relay assembly shown in the datasheet.
- 7/. Add 50 m Ω to the contact resistance shown in the datasheet.
- 8/. Add 0.025 oz (0.71 g) to the weight of the relay assembly shown in the datasheet.
- 9/. M3 pad to be used only when the relay has a center pin (e.g. ER411M3-12A, 722XM3-26.)

APPENDIX A : Ground Pin Positions



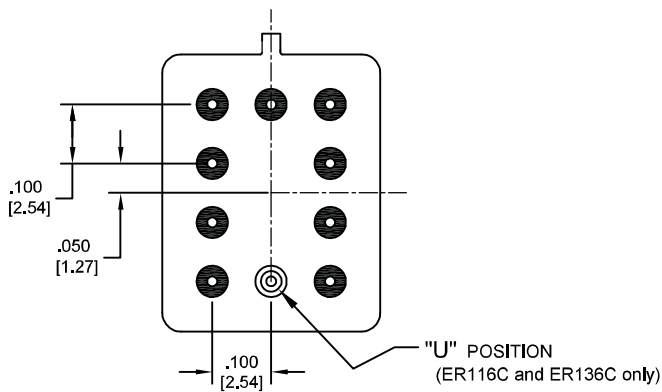
TO-5 Relays:

ER412, ER412T, ER422, ER432, ER432T, 712, 712TN, 400H, 400K, 400V, RF300, RF303, RF341, RF312, RF332, RF310, RF313, RF320, RF323, SI800, SI803, RF700, RF703



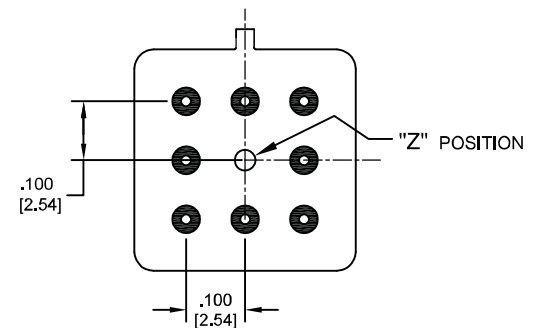
TO-5 Relays:

ER411, RF311, RF331



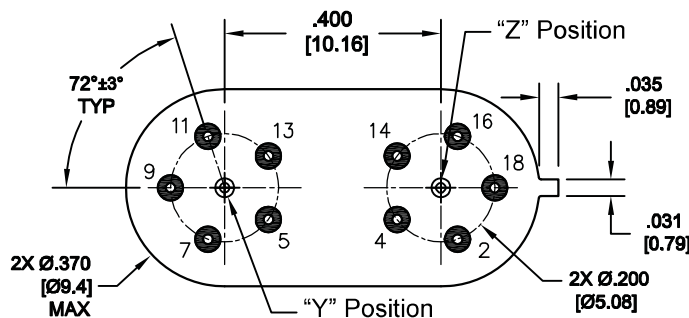
Centigrid® Relays:

RF180, ER116C, 122C, ER136C



Centigrid® Relays:

RF100, RF103, ER114, ER134, 172



Loopback Relays:

LB363

NOTES

- Indicates ground pin position
- Indicates glass insulated lead position
- ⊙ Indicates ground pin or lead position depending on relay type

1. Terminal views shown
2. Dimensions are in inches (mm)
3. Tolerances: $\pm .010$ ($\pm .25$) unless otherwise specified
4. Ground pin positions are within .015 (0.38) dia. of true position
5. Ground pin head dia., 0.035 (0.89) ref: height 0.010 (0.25) ref.
6. Lead dia. 0.017 (0.43) nom.

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